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EC MICROWAVE

The door to the RF world

Product Datasheet Product ID: BMBP30R5/4-6PA

Thin Film ceramic Filte BMBP30R5/4-6PA

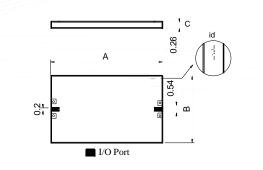
Precautions

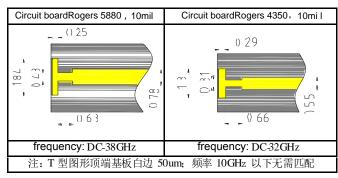
1. The chip is recommended sub-cavity use, both sides of the side wall from about 0.2mm, surface distance Cover about 3mm, the chip ports are interchangeable;

2. Chip recommended low-stress conductive adhesive (such as ME8456) bonding;

3. Chip should be installed in Kovar (recommended) or molybdenum copper with ceramic thermal expansion coefficient(6.7ppm / °C) on the carrier, the carrier thickness \geq 0.2mm;

4 circuit board micro-chip wire bonding connection, it is recommended microstrip bonding at mining T-type structure to match, T-size as right





Features

high-precision film processing technology	
high performance, low temperature drift, high power	
Ceramic substrate, 50Ω coplanar waveguide output	
Gold wire bonding, suitable for multi-chip integrated module applications	

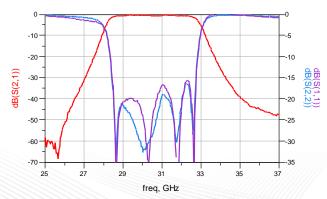
Environmental parameters

Working temperature	-55°C~+85°C
storage temperature	-55°C~+125°C
Maximum input power	35dBm

Electrical Specifications

Center frequency(f0)	30.5
Passband frequency range (GHz)	28.6-32.5
Band fluctuations (dB)	1
Center insertion loss (dB)	1.5
Return loss (dB)	15
Band attenuation (dB)	≥ 40@ 26.5 GHz ≥ 40@3 5.1 GHz

Band rejection & Return loss VS frequency ($T_A = 25^{\circ}C$)

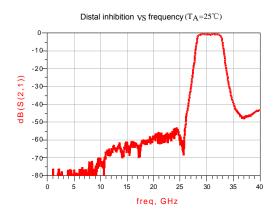


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Passband loss VS frequency $(T_A=25^{\circ}C)$





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